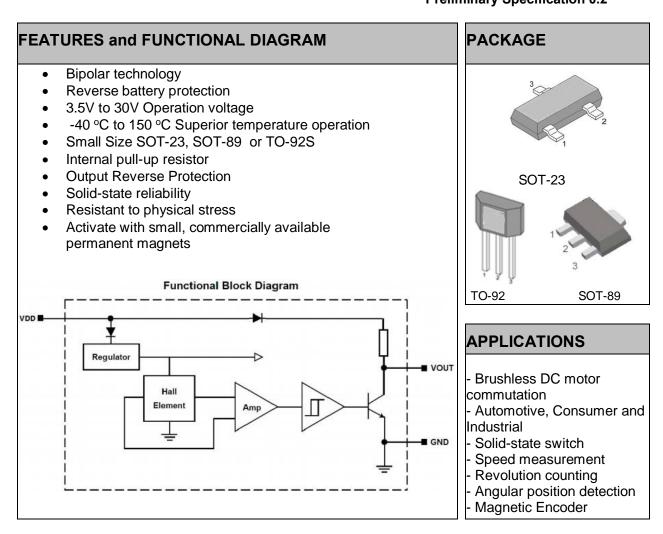


CH415

Industry Product Group

of this product. Contact Cosemi-tech for the latest status
Preliminary Specification 0.2

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemitech assumes no obligation for future manufacture



DESCRIPTION

The CH415 family is a Hall-effect latch designed in bipolar technology. The Hall IC internally includes an on-chip Hall voltage generator, a voltage regulator for operation with supply voltages of 3.5 to 30V, Gnd and Output reverse protection diode, temperature compensation circuitry, small-signal amplifier, Schmitt trigger and an output driver with a pull-up resistor; all in a single package.

It is designed to respond to alternating North and South poles. While the magnetic flux density(B) is larger than operate point (Bop), the output will be turned on (Low), the output is held until the magnetic flux density(B) is lower than release point (Brp), then be turned off (High).

Thanks to its wide operating voltage range 3.5 to 30V and extended temperature range from -40 $^{\circ}$ C to +150 $^{\circ}$ C, it is quite suitable for use in automotive, industrial and consumer applications.

The device is delivered in variety of packages to customers: SOT-23, SOT-89 for surface mount and TO-92S flat for through-hole mount. Both 3-lead packages are RoHS compliant.



Industry Product Group

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status **Preliminary Specification 0.2**

Table of Contents

1. Glossary of Terms	3
2. Product Family Members	3
3. Pin Definitions and Descriptions	3
4. Absolute Maximum Ratings	4
5. ESD protections	4
6. Function Description	4
7. Definition of Switching Function	5
8. CH415 Series Parameters Specification	5
9. Test Conditions	6
10.Typical Application Circuit	6
11.Typical Output Waveform	6
12. Package Information	7



Industry Product Group

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status **Preliminary Specification 0.2**

1. Glossary of Terms

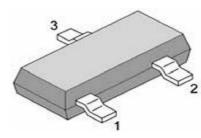
MilliTesla (mT),	Gauss Units of magnetic flux density: 1mT = 10 Gauss
RoHS	Restriction of Hazardous Substances
ESD	Electro-Static Discharge
BLDC	Brush-Less Direct-Current
Operating Point (B _{OP})	Magnetic flux density applied on the branded side of the package which turns the output driver ON (VOUT = low)
Release Point (B _{RP})	Magnetic flux density applied on the branded side of the package which turns the output driver OFF (VOUT = high)

2. Product Family Members

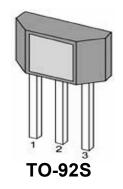
Part Number	Marking ID	Description
CH415SR	C415	Bipolar latching, Hall-effect digital sensor IC, SOT-23-3L package, tape and reel packing (3000 units per reel)
CH415TB	C415	Bipolar latching, Hall-effect digital sensor IC, flat, TO-92S package, bulk packing (1000 units per bag)
CH415ER	C415	Bipolar latching, Hall-effect digital sensor IC, SOT-89-3L package, tape and reel packing (1000 units per reel)

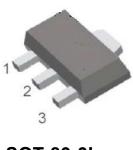
3. Pin Definitions and Descriptions

SOT-23 (AT and ET)	TO-92S (A and A-T)	SOT-89 (BT)	Name	Туре	Function
1	1	1	VDD	Supply	Supply Voltage pin
2	3	3	OUT	Output	Collector Output pin(include pull-up Resistor)
3	2	2	GND	Ground	Ground pin



SOT-23-3L









CH415

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech



Industry Product Group

assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status Preliminary Specification 0.2

4. Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Units
Supply Voltage	VDD	-	40	V
Reverse Voltage	VRDD	-	-40	V
Supply Current	IDD	-	50	mA
Output Voltage	VOUT	-0.3	40	V
Output Current	IOUT	-	50	mA
Operating Ambient temperature	TA	-40	150	°C
Storage Temperature	TS	-50	150	°C
Junction temperature	TJ		165	°C
Magnetic Flux	No Limit			Gauss

Note: Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolutemaximum- rated conditions for extended periods may affect device reliability.ESD Protection

5. ESD protections

Parameter	Value	Unit
All pins ¹⁾	+/-2	kV
All pins ²⁾	+/-200	V

1) HBM (human body model, 100pF, 1.5 kohm) according to MIL 883C, Method 3015.7 or EIA/JESD22A114-A

2) acc. Machine Model: C=200pF; R=0ô

6. Function Description

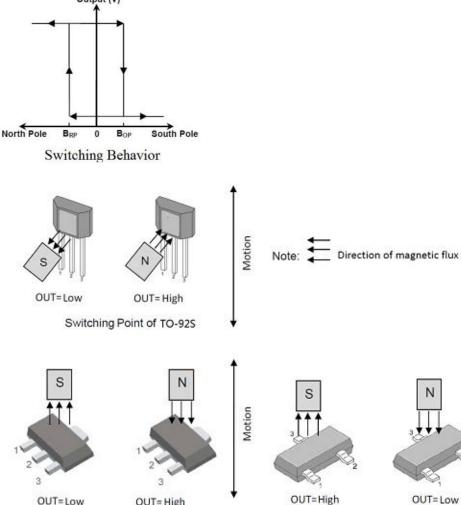
The CH415 exhibits latch magnetic switching characteristics. Therefore, it requires both south and north poles to operate properly.

The device behaves as a latch with symmetric operating and release switching points (BOP=|BRP|). This means magnetic fields with equivalent strength and opposite direction drive the output high and low.

Removing the magnetic field (B 0) keeps the output in its previous state. This latching property defines the device as a magnetic memory.

A magnetic hysteresis BHYST keeps BOP and BRP separated by a minimal value. This hysteresis prevents output oscillation near the switching point.





OUT=Low OUT=High Switching Point of SOT-89-3L

8. CH415 Parameters Specification

The voltages are referred to GND.

3.5V < VD	D < 30V; TJ =-40 to 150°C, u	inless otherwise specified.				
Symbol	Parameter	Test Condition	Min	Тур	Max	Units
VDD	Supply voltage	Operating	3.5	5	30	V
IDD	Supply Current	B <brp< td=""><td></td><td>4</td><td>9</td><td>mA</td></brp<>		4	9	mA
VDSon	Output saturation voltage	lout=15mA, B>BOP			0.4	V
I _{OFF}	Output Leakage Current	B <brp, vout="30V</td"><td></td><td></td><td>10</td><td>uA</td></brp,>			10	uA
T _R	Output rise time	RL=1Kohm, CL=20pF			1.5	uS
T _F	Output fall time	RL=1Kohm, CL=20pF			1.5	uS
Fsw	Maximum Switching Frequency				100	KHz
R _{PU}	Internal pull up resistor			22		Kohm
B _{OP}	Magnetic operating point	TA=25°C	5	50	100	Gauss
B _{RP}	Magnetic release point	TA=25°C	-100	-50	-5	Gauss
B _{HYST}	Magnetic hysteresis window	TA=25°C B _{OP} -B _{RP}	60	100	140	Gauss

Switching Point of SOT-23-3L



Industry Product Group

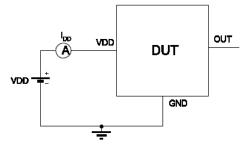
This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status

Preliminary Specification 0.2

9. Test Conditions

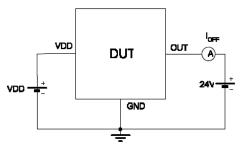
Note : DUT = Device Under Test

Supply Current



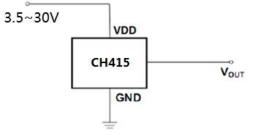
Note 1 - The supply current _{DD} represents the static supply current. OUT is left open during measurement.

Note 2 - The device is put under magnetic field with B<B_{re}. Output Leakage Current

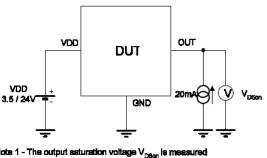


Note 1 - The device is put under magnetic field with B<B_{RP}

10. Typical Application Circuit



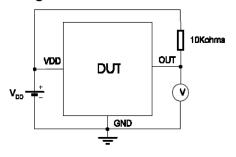
Output Saturation Voltage



Note 1 - The output saturation voltage V_{D6on} is measured at V_{DD} = 3.5V and V_{DD} = 24V

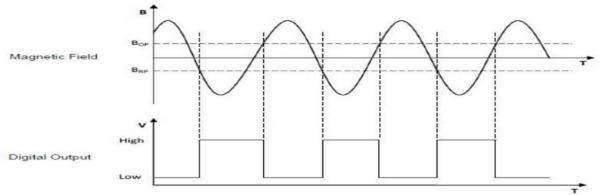
Note 2 - The device is put under magnetic field with B>B_{OP}.

Magnetic Thresholds



- Note 1 B_{OP} is determined by putting the device under magnetic field awept from E_{RPmin} up to B_{OPmax} until the output is awitched on.
- Note 2 B_{RP} is determined by putting the device under magnetic field swept from $E_{\rm OPmax}$ down to $B_{\rm RPmin}$ until the output is switched off.

11. Typical Output Waveform (The TO-92S package as an example)





CH415

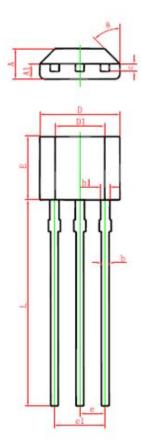
Industry Product Group

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status **Preliminary Specification 0.2**

12. Package Information:

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
	SOT-23 Package Thermal Resistance			301		°C/W
RTH	TO-92S Package Thermal Resistance			230		°C/W
	SOT-89 Package Thermal Resistance			230		°C/W

PACKAGE DESIGNATOR TO-925





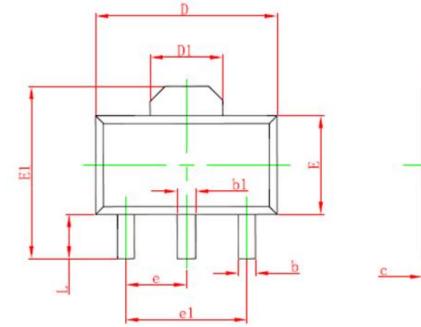
Symbol	Dimensions	In Millimeters	Dimension	s In Inches
	Min.	Max.	Min.	Max.
А	1.420	1.620	0.056	0.064
A1	0.660	0.860	0.026	0.034
b	0.350	0.480	0.014	0.019
b1	0.400	0.550	0.016	0.022
с	0.360	0.510	0.014	0.020
D	3.900	4.100	0.154	0.161
D1	2.280	2.680	0.090	0.106
E	3.050	3.250	0.120	0.128
e	1.270	TYP.	0.050	TYP.
e1	2.440	2.640	0.096	0.104
L	15.100	15.500	0.594	0.610
θ	45°	TYP.	45° TYP.	

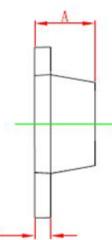


This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status

Preliminary Specification 0.2







Sumbal	Dimensions In Millimeters		Dimension	s In Inches	
Symbol	Min.	Max.	Min.	Max.	
A	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
с	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550 REF. 0		0.061	0.061 REF.	
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
e	1.500	1.500 TYP.		TYP.	
e1	3.000	TYP.	0.118 TYP.		
L	0.900	1.200	0.035	0.047	



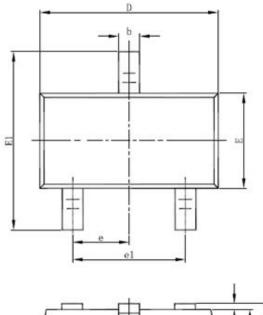
Cosemitech (Shanghai) Co., Ltd.

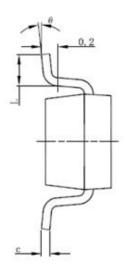


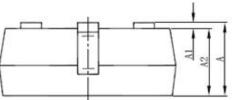
Industry Product Group

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status **Preliminary Specification 0.2**

PACKAGE DESIGNATOR SOT-23 - 3L







0 1 1	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°





This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice and Cosemi-tech assumes no obligation for future manufacture of this product. Contact Cosemi-tech for the latest status

Preliminary Specification 0.2

Information furnished is believed to be accurate and reliable. However, Cosemitech assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Cosemi-tech. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. Cosemitech products are not authorized for use as critical components in life support devices or systems without express written approval of Cosemitech.

The Cosemitech logo is a registered trademark of Cosemitech